

Terahertz to UV Generalized Magnetooptic ellipsometry on ZnMnSe: Giant Kerr effect, band-to-band transitions, and charge transport parameters



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Our message

I. Kerr rotation in paramagnetic ZnMnSe

II. Optical anisotropy found in ZnMnSe, probably due to in-plane strain, or atomic ordering.

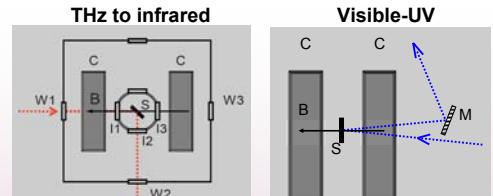
III. Zeeman splitting of the conduction bands as function of Mn content.

IV. Free charge charge carrier parameters of ZnMnSe.

Experiment and model

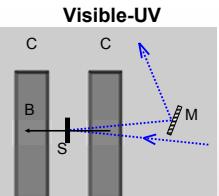
- ✓ Magneto-Optic Generalized Ellipsometry (MOGE) at RT on ZnSe and Zn_{1-x}Mn_xSe ($x=0, 0.13, 0.28$) in the spectral range from 70 to 650 cm⁻¹ and from 1.2 to 3.4 eV.
- ✓ Isotropic model dielectric function (MDF) for ZnSe, and ZnMnSe (Phys. Rev. B **70**, 04513, (2004))
- ✓ Observation of in-plane anisotropy in ZnMnSe (in absence of a magnetic field)
- ✓ Anisotropic MDF of ZnMnSe
- ✓ MOGE (Kerr rotation) measurements of ZnSe and Zn_{1-x}Mn_xSe ($x=0, 0.13, 0.28$)
- ✓ MDF for Zeeman splitting in ZnMnSe (magnetic field induced birefringence)
- ✓ Charge transport parameters of low chlorine doped ZnMnSe

Setup



MBE (U. Karlsruhe)

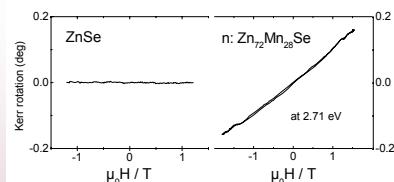
~2 nm Oxide
n:Zn_{1-x}Mn_xSe
[001] GaAs



low chlorine doped
Zn_{1-x}Mn_xSe
 $x=0, 0.13, 0.28$

Experimental results

Kerr rotation measurements



MOGE measurements in quasi-Kerr configuration for ZnSe, and Zn₇₂Mn₂₈Se. The Zn₇₂Mn₂₈Se sample shows a paramagnetic response for a photon energy corresponding to the band-to-band transition, while in ZnSe no Kerr rotation is detected.

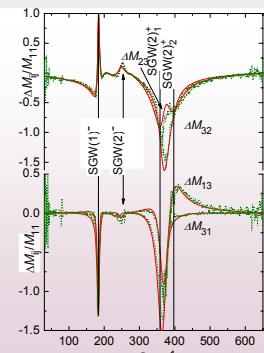
Free charge carrier parameters

Γ-Point CB effective mass

	$N[10^{17}\text{cm}^{-3}]$	$m^*[m_0]$	$\mu[10^2\text{cm}^2/(\text{Vs})]$
GaAs-sub.	10.5(1)	0.071(1)	20.5(1)
ZnMnSe	4.9(2)	0.086(2)	3.0(2)

corresponds to kp-calculations of the Γ-Point CB effective mass for Zn_{0.87}Mn_{0.13}Se

Hofmann, Schade, Schubert, et al., Appl. Phys. Lett. **88**, 042105 (2006)



Isotropic

$$\varepsilon(\omega) = \begin{pmatrix} 1 & 0 & 0 \\ 0 & 1 & 0 \\ 0 & 0 & 1 \end{pmatrix} \frac{1}{2} (\varepsilon_{||} + \varepsilon_{\perp}) + \begin{pmatrix} 1 & 0 & 0 \\ 0 & -1 & 0 \\ 0 & 0 & 0 \end{pmatrix} \frac{1}{2} (\varepsilon_{||} - \varepsilon_{\perp}) + \begin{pmatrix} 0 & i & 0 \\ -i & 0 & 0 \\ 0 & 0 & 0 \end{pmatrix} \frac{1}{2} (\varepsilon_{+} - \varepsilon_{-})$$

In-plane birefringence

M_{12}

$\frac{1}{2}(\varepsilon_{||} + \varepsilon_{\perp})$

Magnetic induced birefringence

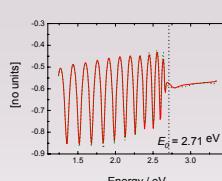
Magnetic induced birefringence

M_{12}

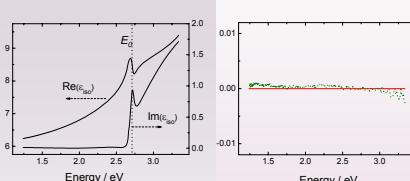
M_{12}

$\frac{1}{2}(\varepsilon_{+} - \varepsilon_{-})$

Materials



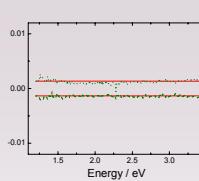
The real and imaginary parts of the isotropic dielectric function obtained from the best match analysis of the GE experimental data.



Same as above.

(not detectable)

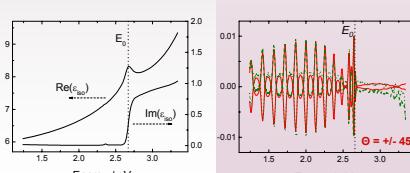
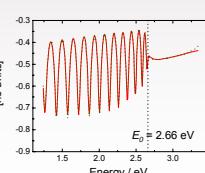
The Mueller matrix element M_{14} used to detect in-plane birefringence shows no signal in the studied spectral range.



No signal was detectable from the MOGE experiment as shown by the M_{23} and M_{32} elements.

(not detectable)

Zn₇₂Mn₂₈Se



A significant difference between the parallel and perpendicular dielectric function was found for ZnMnSe.

12 meV conduction band splitting energy detected in $\varepsilon_{||}$ and ε_{\perp} at $\mu_0 H = 1.8$ T.